Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	15453	semiconductor and porous and (dielectric or insulat$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/22 15:16
L2	4539	1 and (dielectric adj constant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/22 15:17
L3	2950	2 and (open$3 or groove or (contact adj hole))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/22 15:19
L4	856	3 and (low adj k)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/22 15:20
L5	1284	2 and (low adj k)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/22 15:20
L6	168	5 and (contact adj hole)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/22 15:21